# VS-1ENH01-M3, VS-1ENH02-M3

Vishay Semiconductors



# Ultrafast Rectifier, 1 A FRED Pt<sup>®</sup>



Cathode O Anode

### LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	1 A			
V <sub>R</sub>	100 V, 200 V			
V <sub>F</sub> at I <sub>F</sub>	0.69 V			
I <sub>FSM</sub>	40 A			
t <sub>rr</sub> (typ.)	23 ns			
T <sub>J</sub> max.	175 °C			
Package	SMP (DO-220AA)			
Circuit configuration	Single			

### **FEATURES**

- Very low profile typical height of 1.0 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- For PFC, CRM snubber operation
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency, freewheeling, DC/DC converters, PFC, and in snubber industrial and automotive applications.

### **MECHANICAL DATA**

Case: SMP (DO-220AA)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002, meets JESD 201 class 2 whisker test

Polarity: color band denotes cathode end

ABSOLUTE MAXIMUM RATINGS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse	VS-1ENH01-M3	M		100	V	
voltage	VS-1ENH02-M3	V <sub>RRM</sub>		200	v	
Average rectified forward current		I <sub>F(AV)</sub>	T <sub>C</sub> = 168 °C	1	^	
Non-repetitive peak surge current		I <sub>FSM</sub>	$T_J = 25 \text{ °C}, 10 \text{ ms}$ sine pulse	40	A	
Operating junction and st	orage temperatures	TJ, T <sub>Stg</sub>		-55 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage,	VS-1ENH01-M3	V <sub>BR</sub> , I <sub>-</sub> = 100 µA		100	-	-		
blocking voltage	VS-1ENH02-M3	V <sub>R</sub>			-	-	V	
Forward valtage		V	I <sub>F</sub> = 1 A	-	0.86	0.92	v	
Forward voltage		V <sub>F</sub>	٧F	I <sub>F</sub> = 1 A, T <sub>J</sub> = 150 °C	-	0.69	0.74	
Reverse leakage current		I <sub>R</sub>	$V_R = V_R$ rated	-	-	2	μA	
			$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	20		
Junction capacitance		CT	V <sub>R</sub> = 200 V	-	8	-	pF	

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		-	23	-	
Reverse recovery time	t <sub>rr</sub>	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_{rr} = 0.25 \text{ A}$		-	-	28	
		T <sub>J</sub> = 25 °C	I <sub>F</sub> = 1 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 100 V	-	14	-	A nC
		T <sub>J</sub> = 125 °C		-	22	-	
Peak recovery current	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	1.7	-	
		T <sub>J</sub> = 125 °C		-	2.7	-	
Reverse recovery charge Q <sub>rr</sub>	0	T <sub>J</sub> = 25 °C		-	10	-	
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	29	-	

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Thermal resistance, junction mount		R <sub>thJM</sub> <sup>(1)</sup>	Infinite heatsink	-	7	9	°C/W
Thermal resistance, junction to ambient		R <sub>thJA</sub>	PCB footprint 4.8 mm x 4.8 mm	-	107	-	0/10
Approximate weight					0.024		g
VS-1ENH01-M3				1H1			
Marking device	VS-1ENH02-M3		Case style SMP (DO-220AA)	1H2			

#### Note

<sup>(1)</sup> Thermal resistance junction to mount follows JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

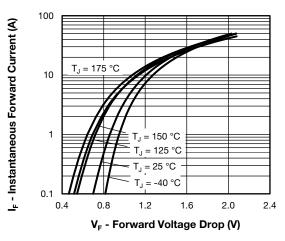


Fig. 1 - Typical Forward Voltage Drop Characteristics

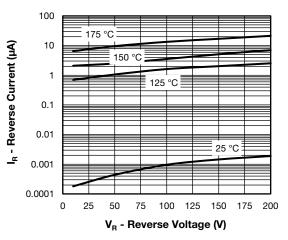
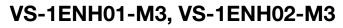


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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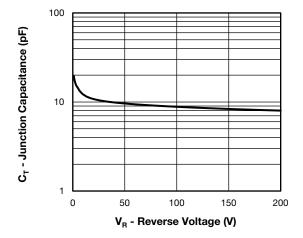


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

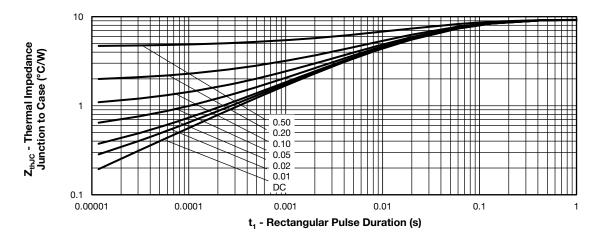
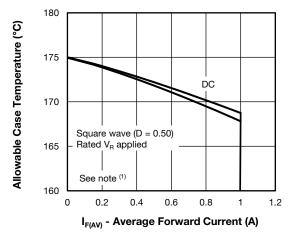
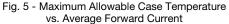


Fig. 4 - Transient Thermal Impedance, Junction to Case



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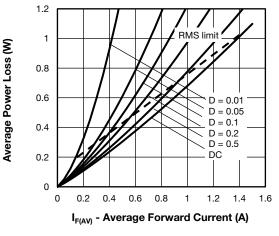


Fig. 6 - Forward Power Loss Characteristics

#### Note

<sup>(1)</sup> Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;

 $\begin{array}{l} Pd = \textit{forward power loss} = I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (\textit{see fig. 5}); \\ Pd_{REV} = \textit{inverse power loss} = V_{R1} \ x \ I_{R} \ (1 - D); \ I_{R} \ at \ V_{R1} = \textit{rated } V_{R} \end{array}$ 

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# VS-1ENH01-M3, VS-1ENH02-M3

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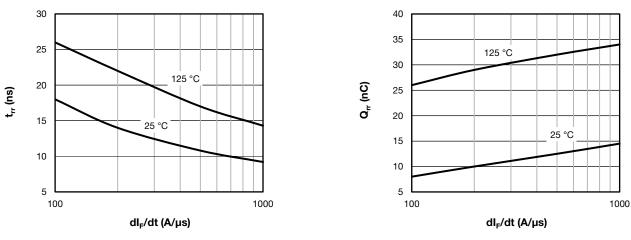


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

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Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

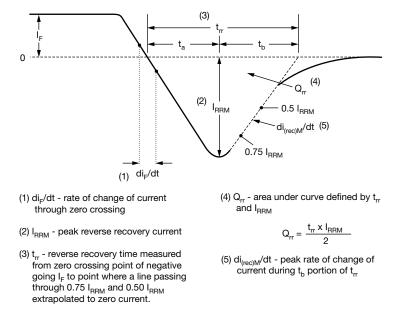


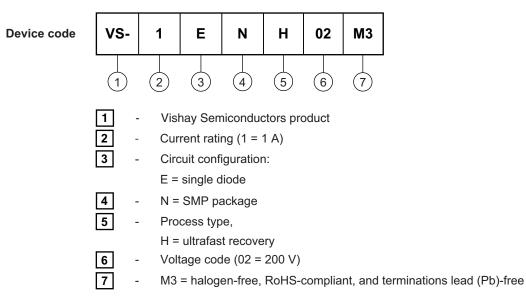
Fig. 9 - Reverse Recovery Waveform and Definitions



# VS-1ENH01-M3, VS-1ENH02-M3

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### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)						
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-1ENH01-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH01-M3/85A	85A	10 000	13" diameter plastic tape and reel			
VS-1ENH02-M3/84A	84A	3000	7" diameter plastic tape and reel			
VS-1ENH02-M3/85A	85A	10 000	13" diameter plastic tape and reel			

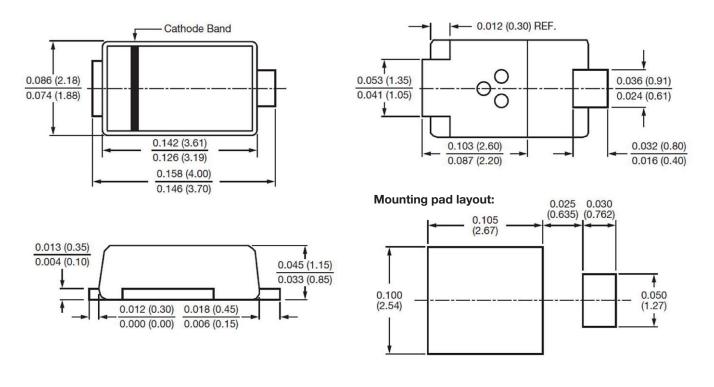
LINKS TO RELATED DOCUMENTS				
Dimensions www.vishay.com/doc?96547				
Part marking information	www.vishay.com/doc?96574			
Packaging information	www.vishay.com/doc?88869			
SPICE model	www.vishay.com/doc?96550			



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# SMP (DO-220AA)

### **DIMENSIONS** in inches (millimeters)





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